

100V, 2 A NPN high power bipolar transistor 9 January 2014

Product data sheet

### 1. General description

NPN high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

PNP complement: PHPT61002PYC

### 2. Features and benefits

- High thermal power dissipation capability
- High temperature applications up to 175 °C
- Reduced Printed Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation

### 3. Applications

- Load switch
- Power management
- Linear mode voltage regulator
- Backlighting apllications

### 4. Quick reference data

Table 1. C	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	100	V
I <sub>C</sub>	collector current		-	-	2	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	6	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = 2 A; $I_B$ = 200 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	80	150	mΩ



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## 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	mb	C
2	E	emitter		в-
3	E	emitter		
4	В	base	មូចូត្	E sym123
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	Syll123

## 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PHPT61002NYC	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669				

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT61002NYC	1002NCA

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### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

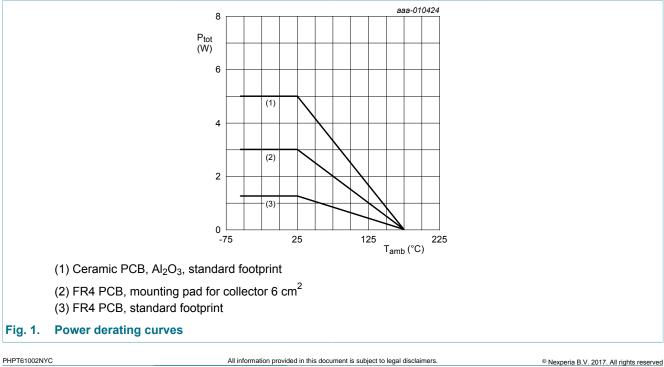
Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	100	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	100	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	7	V
I <sub>C</sub>	collector current			-	2	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	6	А
I <sub>B</sub>	base current			-	0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	1.25	W
			[2]	-	3	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated mounting pad for collector 6 cm<sup>2</sup>.

[3] Device mounted on an ceramic PCB;  $AI_2O_3$ ; standard footprint.

[4] Power dissipation from junction to mounting base.

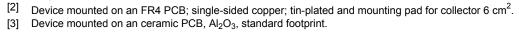


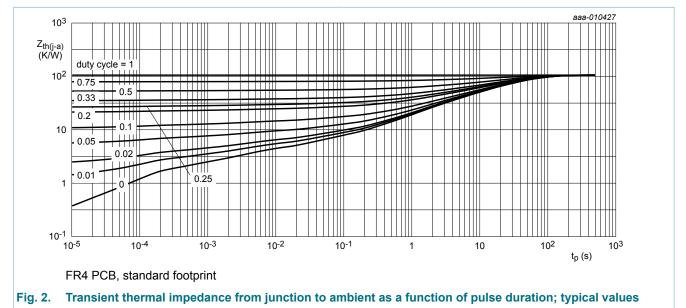
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### 9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	115	K/W
			[2]	-	-	50	K/W
			[3]	-	-	30	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	6	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

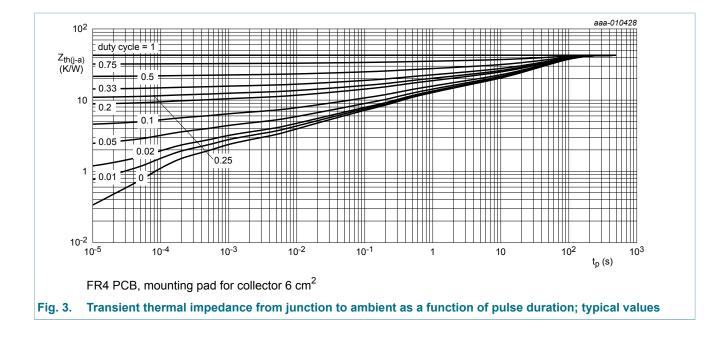




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## **10. Characteristics**

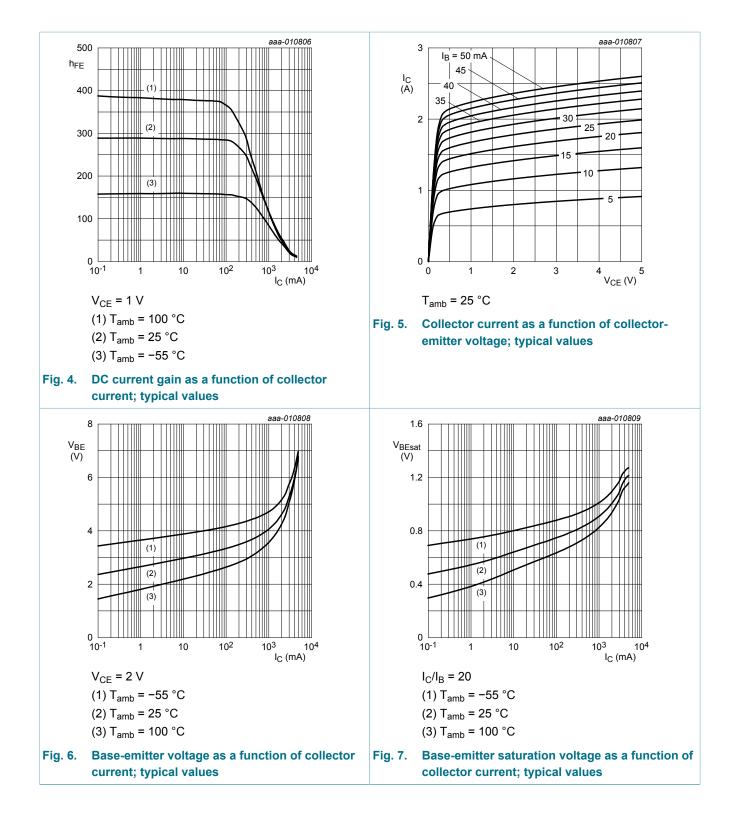
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB}$ = 80 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
	current	V <sub>CB</sub> = 80 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	50	μA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = 80 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C	-	-	100	nA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 7 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 1.5 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	100	200	-	
		$\begin{split} V_{CE} &= 10 \text{ V}; \text{ I}_{C} = 500 \text{ mA};  t_{p} \leq 300  \mu\text{s}; \\ \delta \leq 0.02 ;  T_{amb} = 25 ^{\circ}\text{C}; \text{ pulsed} \end{split}$	150	250	-	
		$V_{CE}$ = 10 V; I <sub>C</sub> = 1 A; t <sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02 ; T <sub>amb</sub> = 25 °C; pulsed	80	200	-	
		$V_{CE} = 10 \text{ V}; \text{ I}_{C} = 2 \text{ A}; \text{ pulsed};$ $t_{p} \leq 300  \mu\text{s};  \delta \leq 0.02 ;  \text{T}_{amb} = 25 ^{\circ}\text{C}$	20	140	-	
		$\label{eq:VCE} \begin{array}{l} V_{CE} \texttt{=} \ \texttt{10} \ V; \ I_{C} \texttt{=} \ \texttt{3} \ A; \ t_{p} \texttt{\leq} \texttt{300} \ \mu \texttt{s}; \\ \delta \texttt{\leq} \ \texttt{0.02} \ ; \ T_{amb} \texttt{=} \texttt{25} \ ^{\circ}C; \ \texttt{pulsed} \end{array}$	10	100	-	
V <sub>CEsat</sub>	collector-emitter	$I_{C}$ = 0.5 A; $I_{B}$ = 50 mA; $T_{amb}$ = 25 °C	-	50	75	mV
	saturation voltage	$I_{\rm C}$ = 2 A; $I_{\rm B}$ = 200 mA; pulsed;	-	160	300	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_{amb}$ = 25 °C	-	80	150	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$\begin{split} &I_{C} = 1 \; A; \; I_{B} = 50 \; mA; \; pulsed; \\ &t_{p} \leq 300 \; \mus; \; \overline{o} \leq 0.02 \; ; \; T_{amb} = 25 \; ^{\circ}C \end{split}$	-	0.92	1	V
		$\begin{split} &I_{C}=\text{2 A; }I_{B}=\text{200 mA; pulsed;} \\ &t_{p}\leq\text{300 }\mu\text{s; }\delta\leq0.02\text{ ; }T_{amb}=\text{25 °C} \end{split}$	-	1.08	1.2	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE}$ = 2 V; I <sub>C</sub> = 0.1 A; T <sub>amb</sub> = 25 °C	-	0.68	0.85	V
t <sub>d</sub>	delay time	$V_{CC}$ = 12.5 V; I <sub>C</sub> = 1 A; I <sub>Bon</sub> = 0.05 A;	-	20	-	ns
t <sub>r</sub>	rise time	I <sub>Boff</sub> = -0.05 A; T <sub>amb</sub> = 25 °C	-	300	-	ns
t <sub>on</sub>	turn-on time		-	320	-	ns
t <sub>s</sub>	storage time		-	830	-	ns
t <sub>f</sub>	fall time		-	470	-	ns
t <sub>off</sub>	turn-off time	-	-	1300	-	ns
f <sub>T</sub>	transition frequency	$V_{CE}$ = 10 V; I <sub>C</sub> = 100 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	-	140	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	11	-	pF

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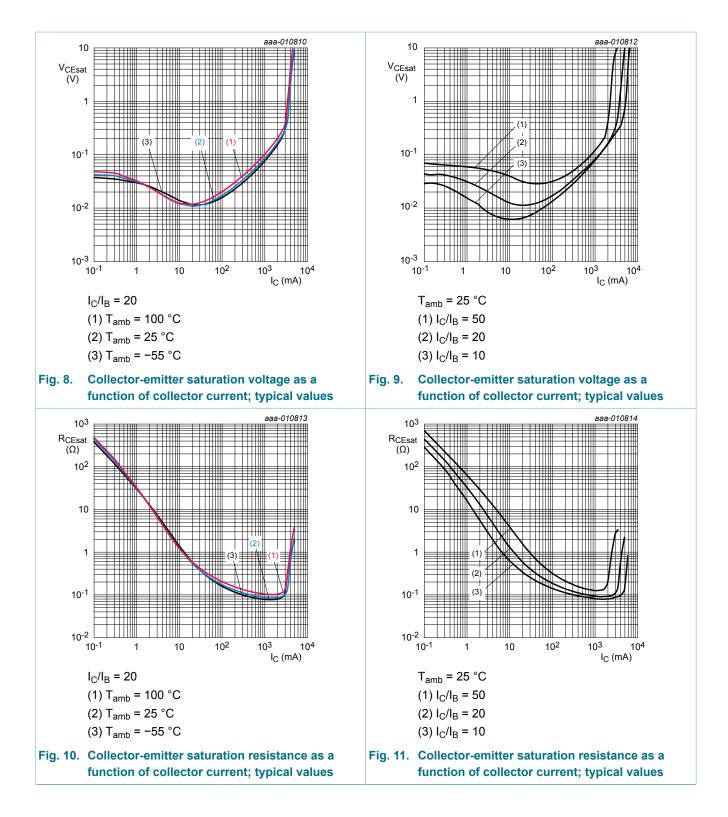
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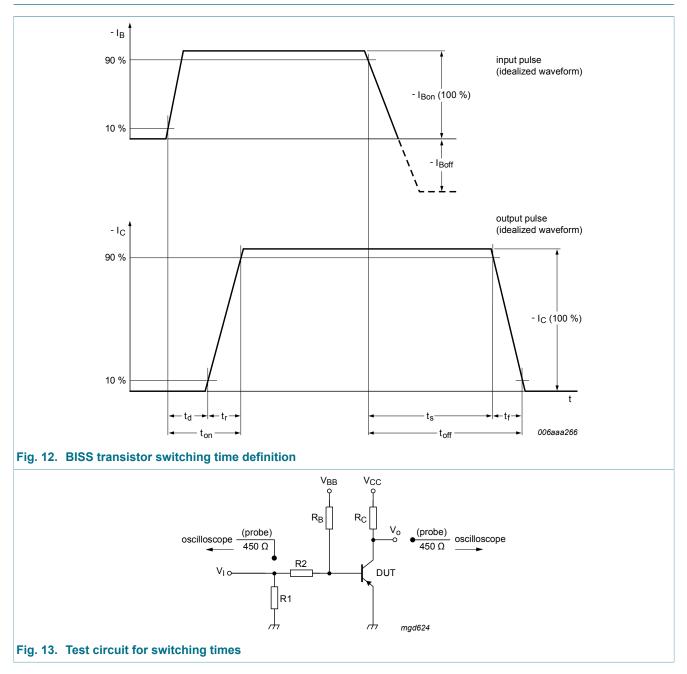
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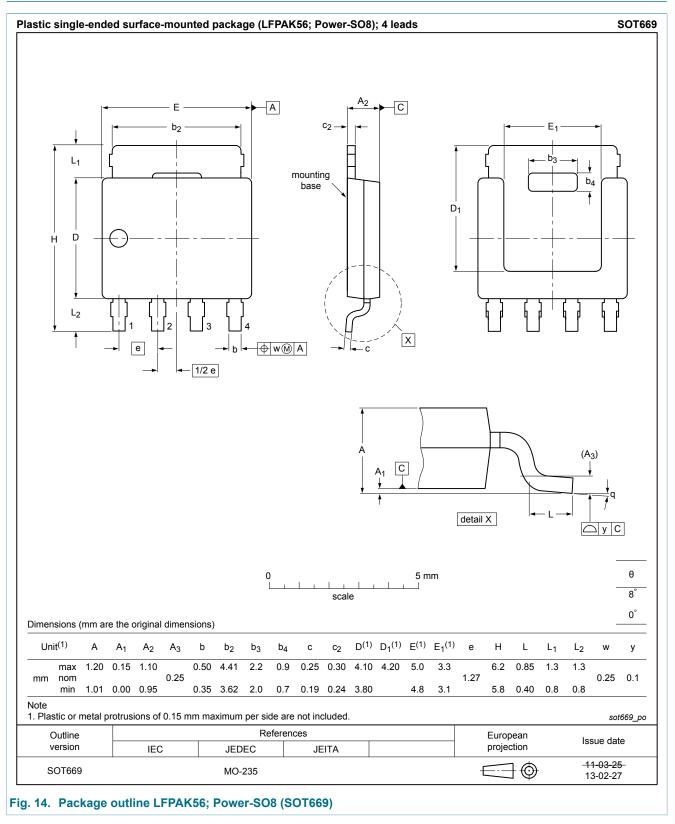
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### **11. Test information**

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### 12. Package outline

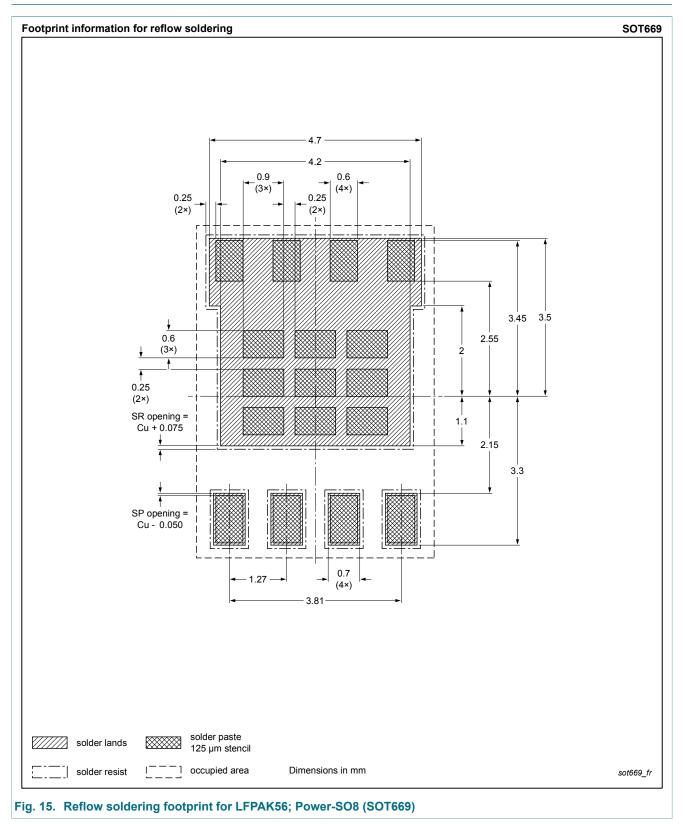


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### 13. Soldering



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## 14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PHPT61002NYC v.1	20140109	Product data sheet	-	-			

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### **15. Legal information**

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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